A 20-Gb/s Full-Rate Linear Clock and Data Recovery Circuit With Automatic Frequency Acquisition

Jri Lee, Member, IEEE, and Ke-Chung Wu

Abstract—A 20-Gb/s full-rate clock and data recovery circuit employing a mixer-type linear phase detector and automatic frequency locking technique is described. The phase detector achieves high-speed operation by mixing the clock with the data-transition pulses, providing output proportional to the phase error. The frequency acquisition loop utilizes the data phases rather than the clock phases to distill the frequency difference, and no external reference is used in this design. Fabricated in 90-nm CMOS technology, this circuit reveals rms and peak-to-peak jitter of 480 fs and 4.22 ps in response to a $2^{31} - 1$ PRBS on the recovered clock while consuming 154 mW from a 1.5-V supply.

Index Terms—Bit error rate (BER), clock and data recovery (CDR), frequency detector (FD), jitter generation, jitter tolerance, linear phase detector (PD).

I. INTRODUCTION

Clock and data recovery (CDR) circuits have found extensive usage in modern communication systems. Fig. 1(a) summarizes the data rate of representative CMOS circuits published since 1995. It can be clearly seen that the speed of the circuits improves even faster than that of the devices (the device transit frequency $f_T$ improves only 2.3 times from 0.18-µm to 90-nm nodes [1]). This is largely due to the continuous progression of CDR architectures and circuit techniques. In addition, the power efficiency also improves steadily approximately 1.4 times per year, which is primarily attributed to scaling. Unfortunately, the scaling of analog circuits has less influence on speed because the passive devices and interconnects do not scale. Overall, novel architectures, new broadband circuit techniques, and advanced processes are essential for modern CDR design.

Based on the operation of phase detectors (PDs), CDR circuits are traditionally classified into two categories [2]: binary (bang-bang or Alexander) [3] and linear (Hogge) [4]. The jitter transfer and jitter tolerance of the former vary with the input (phase) magnitude. Linear PDs, on the other hand, present a straightforward design flow, since a typical linear PLL model can fit the requirement very well. However, in contrast to their binary counterparts, linear CDR circuits thus far confront a speed limitation at around 10 Gb/s. This is primarily because the linear operation usually involves pulse generation and pulsewidth comparison, both of which are very challenging at high speed. Let us take a Hogge PD [Fig. 2(a)] as an example. In 90-nm CMOS, since the rise and fall times of a fan-out-of-4 inverter are as large as 33 ps, it is impossible to build a digital PD running beyond 10 Gb/s. Current-mode logic (CML) can speed up the operation to some extent, but the fundamental issue still remains. Fig. 2(b) shows the simulated linear range of standard full-rate Hogge PDs designed with CML topologies in 90-nm and 0.13-µm CMOS technologies. Even though the circuits are optimized (e.g., adding proper delays to compensate for the skew), the operation range still drops dramatically after 1 Gb/s. This is because at high speed, the finite transition times compress the width of the reference pulses, making the PD characteristic imbalanced. Other limitations of the Hogge type PDs were analyzed in [2]. $CK$-to-$Q$ delay of the flip-flops in a Hogge PD could never be fully compensated over process, supply voltage, and temperature (PVT) variations. Half-rate [5] or even quarter-rate operation relaxes the stringent speed requirement. In fact, parallelism has been widely adopted in modern CDR designs [6], [7]. However, it also causes other design issues. For example, the phase error between the multiple clock phases could cause significant skew and jitter, potentially requiring calibration circuitry that could increase design complexity as well as power consumption. The large area would be another negative concern if we were to develop a multi-channel receiver [8].

Another design consideration is the implementation of a frequency acquisition loop. The Pottbacker frequency detector (FD) [9] and other similar approaches [10], [11] can determine...
the frequency error without an external reference, but they require quadrature clocks to do so. For sub-rate architectures, this type of frequency detection needs to further break down the clock phases, making the clock generation and distribution more difficult. Creating multiphase clocks with $LC$ oscillators would lead to higher phase noise as well, since the oscillators may operate at frequencies away from the resonance of the tanks [11]. In this paper, we propose an automatic frequency detection loop that activates itself as the loop is out of lock, and turns off when the frequency acquisition is accomplished. Minimizing the hardware and power consumption, this technique also requires no external reference nor lock detector. We discuss the realization of the FD in Section II.

This paper presents the design and analysis of a 20-Gb/s CDR circuit in 90-nm CMOS technology. Using a mixer-type full-rate linear PD structure, this work completely eliminates the above issues. The reference-free frequency detector makes use of the by-product of the PD, necessitating no quadrature clocks and saving significant power. The automatic turn-off function considerably simplifies the design, because the digital blocks for frequency comparison and lock detection are eliminated. The prototype achieves output clock jitter of 480 fs, rms and 4.22 ps, pp in response to a $2^{31} - 1$ PRBS while consuming 154 mW from a 1.5-V supply.

The paper is organized as follows. Section II describes the CDR topology, describing design issues and considerations. Section III presents the building blocks of the circuits. Transistor-level analysis of the blocks is also included. Section IV summarizes the measurement results.

II. CDR ARCHITECTURE

The proposed CDR circuit is shown in Fig. 3(a). It incorporates a full-rate voltage-controlled oscillator (VCO), a linear PD based on a transition detector and mixer, an automatic frequency detector, the corresponding V-to-I converters, and a retiming flip-flop. We describe the operation and requirements of the PD and FD in the following subsections.
A. Phase Detection

As described in Section I, the pulse generation and comparison involved in Hogge PD limit the speed because of the long rise and fall signal edges of the XOR gates and finite \( CK\)-to-\( Q \) delay in the flip-flop. These issues can be alleviated by using a mixer-based phase detector. As shown in Fig. 3(a), the input data passes through a chain of delay cells, providing a total delay (from \( V_A \) to \( V_E \)) approximately equal to half a bit (25 ps). An XOR gate examines this fixed phase difference, creating a pulse nominally equal to 25 ps upon occurrence of data transitions. Acting as a reference for phase detection, this pulse sequence is mixed with the clock from the VCO. To create a rough sketch on the PD operation, we plot conceptual waveforms of important nodes under locked condition in Fig. 3(b).\(^1\) When a data edge is present, the mixer produces an output pulse whose width is proportional to the phase difference between the XOR output and the clock. This result can be used for phase alignment. During consecutive bits, on the other hand, the mixer generates a periodic signal which is in phase with the clock. This signal has a zero average, given that the duty cycle of the clock is 50%. In other words, for random data the mixer provides an average output voltage proportional to the phase error between the two inputs. A \( V\)-to-I converter then translates the voltage into current and injects it into the loop filter. As a result, the center tap \( V_C \) always aligns with the clock, and data sampling can be accomplished in the retiming flip-flop using the falling clock edges.

What happens if the clock duty cycle deviates from 50%? If \((V/I)_{PD}\) were solely driven by the mixer, the distortion would lead to finite residue current and modulate the control voltage. Fortunately, we can apply the complement of the clock (\( \overline{C} \)) into \((V/I)_{PD}\) to overcome this difficulty. Since the clock and the mixer’s output are in phase, it completely cancels out the periodic disturbance for consecutive bits. The \((V/I)_{PD}\) design is presented in Section III-C. As illustrated in Fig. 3(b), \( I_{PD} \) [the output current of \((V/I)_{PD}\)] reveals zero pure output during long runs.

In real operation with finite bandwidth, however, sharp transitions at 20 Gb/s cannot be created. Fortunately, unlike the Hogge PD, this work need not generate narrow pulses at all. At such a high speed, the clock and the XOR outputs become rounded because the higher order harmonics are suppressed. As a result, the phase detection is nothing more than mixing two sinusoidal signals. As illustrated in Fig. 4(a), if the delay is exactly 25 ps, the XOR gate and the clock outputs can be simply modeled as

\[
\begin{align*}
V_{\text{XOR}} &= \begin{cases} 
A \cos(\omega t + \pi), & \text{for data transitions} \\
-A, & \text{for long runs}
\end{cases} \\
CK_{out} &= B \cos(\omega t + \theta)
\end{align*}
\]

(1)

(2)

For simple illustration, we temporarily assume infinite bandwidth and therefore obtain sharp transitions, which is not true in reality. Fig. 4(a) presents more realistic waveforms.

\[\omega = 2\pi \times 20 \text{ GHz} \]

where \(A = 20 \text{ ns} \) and \(B = 10 \text{ ns} \).

In other words, when the data edge is presented, the phase difference is obtained as a near-dc output \( (AB/2) \cos(\theta - \pi) \). The second-order term is filtered out by means of intrinsic parasitics. Simulation suggests a suppression of 34 dB. The fundamental modulation during consecutive bits is eliminated by \( CK \) as described in the previous paragraph. Simulated at the transistor level in 90-nm CMOS, Fig. 4(b) depicts the average output current as a function of phase error. As expected, it presents a sinusoidal characteristic with a PD gain [together with \((V/I)_{PD}\)] of 300 \( \mu \text{A/\text{rad}} \) in the vicinity of origin. A linear operation region of about 180\(^\circ\) is obtained. To compare with the Hogge PD, we also plot the simulated linear ranges as shown in Fig. 4(c). The proposed structure achieves a large operation bandwidth all the way from dc to 40 Gb/s. Note that the sharp pulses of \( I_{PD} \) in Fig. 3(b) do not exist in reality either. Upon phase locking, the output current \( I_{PD} \) would only be modulated by less than 30 \( \mu \text{A} \) at a rate of 20 GHz because of the low-pass filtering effect. Nonetheless, it is equivalent to a 20-GHz periodic phase modulation on the input and is rejected by the limited loop bandwidth of the CDR (\( \approx 15 \text{ MHz} \)).

It is noteworthy that under locked condition, the clock edges always align with the center of the generated pulses, whether or not the delay from \( V_A \) to \( V_E \) (\( \Delta T_{A-E} \)) is exactly 25 ps. Fig. 5 reveals two cases where the delay is longer and shorter than half bit period. Obviously, \( V_C \) still coincides with the clock, keeping an optimal phase for data retiming. Note that the buffered clock...
deviates from 25 ps. Through another flip-flop, the polarity of \( V_A \) and \( V_C \), and the retiming (deviation \( \Delta T_{A-E} \), respectively. Whether \( \Delta T_{A-E} \) is less than 5 ps, such an intrinsic alignment proves robust over PVT variations. To verify it, we examine the sampling points of different conditions in Fig. 6. The clock edge deviates from the data center of 25 ps, which allows us to calculate the deviation of the sampling points over different conditions.

\[ V_{D0} = 1.75V \]
\[ V_{D0} = 1.35V \]
\[ V_{D0} = 1.15V \]

The XOR gate delay is estimated to be less than 5 ps. Such an intrinsic alignment proves robust over PVT variations. To verify it, we examine the sampling points of different conditions in Fig. 6. The clock edge deviates from the data center of 25 ps, which allows us to calculate the deviation of the sampling points over different conditions.

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\[ V_{D0} = 1.15V \]

The reader may also wonder how large the delay error it can tolerate. Using the more accurate model with round (sinusoidal) pulses in Fig. 4(a), we assume the delay deviation is \( \Delta \% \) with respect to a clock period. The imbalanced XOR pulses yield a corresponding factor \( \sin[^{\pi}(1/2 + \Delta \%)] \) for the fundamental term of its Fourier series. The resulting near-dc term now becomes

\[ V_{\text{mixer}} = \frac{AB}{2} \sin \left[ \pi \left( \frac{1}{2} + \Delta \% \right) \right] \cos(\theta - \pi). \tag{4} \]

That is, the input-output characteristic keeps the sinusoidal shape but with lower PD gain. Fig. 7(a) illustrates the average output of PD for different delay deviations. It is obvious that for \( \Delta \% = \pm 25\% \) (deviation = \( \pm 12.5 \) ps), the PD gain in the vicinity of origin gets reduced by 30\%, just as predicted by (4). Simulation suggests the maximum \( \Delta \% \) to be less than 7.1\% with variations of \( \pm 10\% \) supply, 0 \( \sim \) 100\(^\circ\)C temperature, and different corners [Fig. 7(b)]. In other words, the delay needs no additional tracking or control, since it is irrelevant to the clock.

**B. Frequency Acquisition**

Due to the limited lock range, the correct frequency must be acquired before phase locking. Conventional dual-loop architecture [12], [13] requires a local frequency reference. Some referenceless approaches such as Pottbacker frequency detector can avoid the need for a reference by using quadrature clocks to distill the frequency information. We propose here a more compact solution for frequency acquisition.

In this CDR design, the nominal 25-ps delay from \( V_A \) to \( V_E \) implies a 12.5-ps delay from \( V_B \) to \( V_D \), which allows us to extract the frequency difference. Indeed, the 12.5-ps data delay corresponds to a 90\(^\circ\) phase shift of a 20-GHz clock, making it possible to realize a rotational frequency detector without using quadrature clocks. The proposed FD is shown in Fig. 8(a). Here, the clock is sampled by using the PD’s by-product \( V_D \) and \( V_D \), producing two outputs \( Q_1 \) and \( Q_2 \), respectively. Whether \( Q_1 \) is leading or lagging \( Q_2 \) depends on the polarity of the frequency error [Fig. 8(b)]. Similar to the Pottbacker FD in [9], \( Q_1 \) is further sampled by \( Q_2 \) through another flip-flop. The polarity of frequency error \( Q_3 \) is therefore obtained. The up/down signal is subsequently applied to a second V-to-I converter (V/I)\(_{\text{FD}}\), which injects a current into the loop filter and corrects the VCO frequency accordingly. Like the Pottbacker FD, the \( V_B \rightarrow V_D \) delay need not be exactly 12.5 ps. Simulation shows that a range of \( \pm 27\% \) on the delay variation is tolerable for the FD to function properly.

To minimize the disturbance to the VCO, the frequency acquisition should be turned off upon lock and re-enabled if

\[^2\text{As a matter of fact, a precise 90\(^\circ\) separation on adjacent phases is not mandatory. A looser condition (such as 80\(^\circ\) or 100\(^\circ\)) would still allow an FD to achieve similar performance, given that the initial frequency deviation stays within a certain range.}\]
necessary. A simple modification can achieve such a tristate operation. As illustrated in Fig. 8(c), when the phase lock is accomplished, \( Q_1 \) and \( Q_2 \) would stay low and high, respectively. Following the design of [15], we apply \( \overline{Q_2} \) (the reverse of \( Q_2 \)) to \( \overline{(V/I)_{FD}} \) to fulfill the automatic switching off when the frequency acquisition is completed. As compared with typical realizations that usually involve significant peripheral control circuits, this work achieves a compact yet powerful design. The spontaneous operation suppresses undesirable interference onto the loop filter and saves considerable power and area for lock detector, logic controller, and other auxiliary circuits. Note that other FD designs such as [16] using quadrature clocks can achieve graceful shut down function as well, but the FD in [16] requires at least four flip-flops and four NAND gates.

It is instructive to examine the FD operation in detail and quantize the capture range. The states of \( Q_1, Q_2 \) can be characterized in Fig. 9(a), where the rotating direction indicates the sign of the beat frequency. For example, a clockwise rotation suggests the clock frequency \( f_{\text{ck}} \) is less than the data rate \( f_{\text{b}} \). Of course, the rotation rate represents the beat frequency. For such an FD to make a right decision on every sampling, we must require the states of \( Q_1 \) and \( Q_2 \) to jump no more than one step at a time. That is, the average output current \( I_{P_{\text{avg}}} \) remains fixed (either positive or negative) for low frequency error,
forming a binary characteristic. This situation continues until the above condition is violated. To determine the points where $I_{P2,\text{avg}}$ begins to drop, we study one worst case as illustrated in Fig. 9(b). Here, without loss of generality, we assume $f_{\text{CK}}$ is less than $R_b$ and the transition of $V_D$ (and thus $Q_1$) is already very close to the clock edge. Starting from (1, 1), the state either stays at (1, 1) or moves to (0, 1) in the next sampling. As we know, for a PRBS of $2^N-1$, the longest run length between transitions is $N$ bits. Since the longest run accumulates the most error, we can determine the largest beat frequency at which the average output current begins to degrade. That is, after $N$ bits, the sampled $Q_2$ remains high. The boundary condition gives

$$N \cdot \left| \frac{1}{f_{\text{CK}}} - \frac{1}{R_b} \right| = \frac{1}{4f_{\text{CK}}}. \quad (5)$$

It follows that the deviation is given by

$$\Delta f_1 \triangleq \left| f_{\text{CK}} - R_b \right| = \frac{R_b}{4N}. \quad (6)$$

If $N = 7$, for example, the binary range is equal to $\pm 3.6\%$. It can be easily proven that $\Delta f$ is symmetric with respect to the origin. Strictly speaking, the use of $N$ bits as the longest period of error accumulation is not exactly correct because the flip-flops in the FD are single-edge triggered. The actual accumulation time would be longer than $N \cdot (1/R_b)$. For example, the longest distance between two adjacent rising edges in a $2^7-1$ PRBS is 13 bits, so the binary characteristic begins to roll off at around $R_b/(4 \cdot 13)$.

The above analysis is based on the worst-case scenario. In practice, $Q_1$ may stay far away from the clock edge before the $N$-bit long run. The best-case scenario can be shown in Fig. 9(c), where the phase error accumulated over $N$ bits must be less than a half rather than a quarter of a clock cycle in order to maintain a saturated $I_{P2,\text{avg}}$. Thus, the widest binary range would be twice as large as that in (6):

$$\Delta f_2 = \frac{R_b}{2N}. \quad (7)$$

Depending on the initial phase relationship, the binary range in reality lies between the two extremes $\Delta f_1$ and $\Delta f_2$.

The FD performance begins to degrade beyond the binary range, as the sequence of $Q_1$ and $Q_2$ becomes chaotic and the erroneous samplings occur in $F1$. It is expected to see the average output eventually approaching zero as the sequential states of $Q_1$ and $Q_2$ become totally random, i.e., no reliable average on $Q_3$ can be obtained. The vanishing point can be roughly estimated as follows. For random data, the expected interval between two adjacent transitions is two bits. Since $F1$ and $F2$ are single-edge triggered, $V_D$ and $V_D$ on average sample the clock every four bits. Now, if the frequency error is so significant that $(Q_1, Q_2)$ steps more than one state in each sampling, the beat-frequency sequences become totally corrupted and the FD has no way to judge the polarity. Under such a circumstance, we have

$$4 \cdot \left| \frac{1}{f_{\text{CK}}} - \frac{1}{R_b} \right| \geq \frac{1}{2f_{\text{CK}}}. \quad (8)$$

In other words, the capture of the FD is about $\pm 12.5\%$. In fact, the vanishing point is slightly larger than the prediction of (9) because of the finite rising and falling times. Fig. 10 reveals the simulated FD characteristic for a $2^7-1$ input data sequence. Here, the roll-off point locates at 400 MHz as expected. If we set half the peak current as a threshold, the useful working range would be as large as 3.7 GHz, which is well exceeding the VCO tuning range ($\approx 1.1$ GHz). Note that it is more or less subject to change for different initial phase conditions. The wide pull-in range ensures correct operation for the loop.

### III. BUILDING BLOCKS

#### A. VCO and Clock Buffer

The LC-tank VCO incorporated in this design is shown in Fig. 11. The bias current, inductors, and device sizes are properly chosen such that it reaches optimal performance. The resistor $R_{\text{SS}}$ is used to slightly lift up the output common-mode level of $CG_{\text{out}}$ by $100 \sim 200$ mV so as to relax the voltage headroom of the subsequent buffers (realized as differential pairs).

While the 20-GHz clock design is straightforward, clock distribution is relatively challenging. Simulation shows that the
The bandwidth would be decreased. In other words, similar to the small-signal analysis, the differential pair steers the tail current \( I \) completely under large input and presents a flat \( V_{\text{out}} / V_{\text{in}} \) of \( IR \) from dc to approximately the bandwidth \( \omega_n \). Note that the large signal behavior resembles the small-signal response and it can be verified by simulation. The key point is, since the flip-flops require a swing of at least 500 mV, \( R \) must be 150 \( \Omega \) to 200 \( \Omega \) or larger. Otherwise, \( I \) must be increased, which in turn leads to bigger device sizes and larger \( C \). If we were to keep the optimal \( \zeta \) by increasing \( L \), the bandwidth would be decreased. In other words, it is difficult to realize a large swing output by using inductive peaking only. In fact, it is a waste to keep the voltage gain all the way down to dc, because the clock buffer only operates at around 20 GHz. We thus resort to other resonance techniques with higher efficiency.

Another possible approach attempting to deliver large swing is to employ pure inductive loads, which resonates out the parasitic capacitance \( C \) at the desired frequency [Fig. 12(b)]. Indeed, this method produces a swing of \( IR_{P2} \) in the vicinity of \( 1/\sqrt{LC} \), where \( R_{P1} \) represents the loss of \( L \) as an equivalent resistance in parallel. With a quality factor \( Q \) above 4, the buffer in Fig. 12(b) can create a large output swing easily. However, it is very challenging to precisely line up the resonance frequencies of the VCO and the buffer. For instance, if \( Q = 5 \), then a 50% magnitude degradation would occur if the two resonance frequencies deviate from each other by 17%. Practical application thus becomes very hard to implement due to PVT variations. The output swing is not predictable since the \( Q \) of the on-chip inductors is hard to control.

The above difficulties can be alleviated by introducing an underdamped peaking. As depicted in Fig. 12(c), we keep the loading resistors of Fig. 12(a) but reduce the value to \( R_u \). The output swing starts with a lower value of \( IR_{P2} \) from dc and presents a gradual peaking of \( IR_{P2} \) at \( 1/\sqrt{LC} \). Here, we convert the series \( L-R \) network into an equivalent parallel combination \( L-R_{P2} \). The difference between Fig. 12(b) and (c) is that the \( R_{P2} \) in Fig. 12(c) now becomes predictable, because the physical resistor \( R_{P2} \) is fully under our control. In other words,
we degenerate the tuned amplifier of Fig. 12(b) in such a way that its peaking and bandwidth become well-behaved to accommodate the desired operation points. As compared with that in Fig. 12(a), this buffer allows more efficient optimization of the gain and bandwidth. For example, if we choose $\zeta = 0.25$, then the equivalent $Q = 2$ and $R_{\text{eq}} = 4R_{\text{in}}$. To be more specific, this method plays a compromising role between the resistive and inductive loadings, alleviating bandwidth limitation and providing accurate swing control. Note that this structure is totally different from the purely inductive designs such as [18] and [19].

To further increase the bandwidth, we cascade two stages with different peaking frequencies [Fig. 12(c)]. The split peaks enlarge the operation range significantly. In this design, we realize the peaking moderately to ensure a stable operation, i.e., the maximum peak only exceeds the dc gain by 2.7 dB. As a result, the -3-dB bandwidth of this clock buffer is about 24.6 GHz, which provides adequate margin for PVT variations. Note that the two-stage topology also achieves a good isolation for VCO, protecting it from being disturbed by the sampling block to further speed up the circuits. Here we plot the conventional and proposed latches in Fig. 13 to make a comparison. While the peaking technique improves the sampling bandwidth of the $M_1$-$M_2$ pair, it also helps the regeneration of $M_3$-$M_4$. To gain more insight, we first consider the ordinary CML latch without inductors [Fig. 13(a)]. Suppose the latch samples the input data at a position very close to the transition, i.e., the initial output $V_{\text{out},0}$ before the regeneration is very small. It can be shown in [20] that after a half-cycle regeneration, the output $V_{\text{out}}$ becomes:

$$V_{\text{out}} = V_{\text{out},0}\exp\left(\frac{(g_{m3,4}R - 1)T_{\text{CK}}}{2RC}\right).$$  \hspace{1cm} (11)

Here, $T_{\text{CK}}$ denotes the clock period and $g_{m3,4}$ the transconductance of $M_3$-$M_4$. That is, the output increases exponentially with a time constant $\tau_0 = RC/(g_{m3,4}R - 1)$. With the help of inductive peaking, this process is expedited. Redrawing the latch with peaking inductor $L$ and the equivalent model in regeneration mode [Fig. 13(b)], we calculate the output $V_{\text{out}} (= V_X - V_Y)$ again:

$$LC\frac{d^2V_{\text{out}}}{dt^2} + (RC - g_{m3,4}L)\frac{dV_{\text{out}}}{dt} + (1 - g_{m3,4}R)V_{\text{out}} = 0.$$  \hspace{1cm} (12)

For the most flat response [the damping factor $\zeta = (R/2\sqrt{C/L} = 0.7)$], we obtain an explicit solution for

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**Fig. 13.** (a) Regular CML latch. (b) CML latch with inductive peaking. (c) Regeneration speed improvement as a function of $g_{m3,4}R$. 

**B. Retiming Flipflop**

The high data rate needs all blocks to operate in current mode. In this work, we also incorporate inductive peaking in each
\( V_{out}(t) \), which grows up exponentially with a new time constant \( \tau \):\(^3\)

\[
\tau = \frac{2RC}{g_{m3A}R - 2 + \sqrt{g_{m3A}^2R^2 + 4g_{m3A}R - 4}}.
\]

As compared with \( \tau_0 \), the positive-feedback process is accelerated by a factor of

\[
\frac{\tau_0}{\tau} = \frac{g_{m3A}R - 2 + \sqrt{g_{m3A}^2R^2 + 4g_{m3A}R - 4}}{2(g_{m3A}R - 1)} \geq 1. \tag{14}
\]

Note that \( g_{m3A}R \) must be greater than unity to guarantee positive feedback. Fig. 13(c) plots the speed improvement as a function of \( g_{m3A}R \), demonstrating that the inductive peaking unconditionally improves the regeneration. However, aggressive peaking not only risks the regeneration but leads to significant ringing on the output data. Two cases of time domain waveforms with \( g_{m3A}R = 1.1 \) and 2 are shown in the insets of Fig. 13(c) to illustrate such a trade-off. As a result, an improving factor of 1.414 as \( g_{m3A}R = 2 \) has been chosen as an optimal point in this design. The device sizes in our design are also listed in Fig. 13(b). Note that in actual design, the speed may be boosted to a lesser extent due to some other considerations such as power consumption and routing convenience.

C. Mixer, XOR Gate, Delay Cell, and \( V/I \) Converters

The mixer, XOR gate, and delay cell are implemented as inductively-peaked CML topologies as well. Fig. 14 depicts the designs as well as the device sizes. The delay cell is realized as a hysteresis buffer [17] to provide sharp transition with significant delay. As compared with the delay chain in [21] that utilizes eight purely differential pairs with power dissipation of 36 mW, this work generates the same 25-ps delay while consuming only 24 mW. Note that although not necessary in this prototype, external delay tuning could be achieved by adjusting the two tail currents \( I_{SS1} \) and \( I_{SS2} \). Similar to that in [21], the inductors are implemented as stacked spirals to minimize the area and alleviate the routing. The four delay cells are carefully laid out with balanced routing and loading to minimize static error in the retiming flip-flop. Fig. 14(d) illustrates the delayed waveforms simulated in transistor level.

\[^3\]The second solution of \( V_{out}(t) \) decays.
The \((V/I)_{\text{FD}}\) design is depicted in Fig. 15(a), where two differential pairs \(M_1-M_2\) and \(M_3-M_4\) steer two identical current sources. As mentioned in Section II.A, the duty cycle error can be fully tolerated if the two pairs and the associated current sources are matched. Unlike the conventional (XOR-based) linear PDs that potentially suffer from imbalanced clock skews, this approach alleviates the VCO design requirements substantially. Fig. 15(b) depicts the \((V/I)_{\text{FD}}\) design. Note that the asymmetry of the up and down paths in Fig. 15(a) and (b) is not an issue, since they are dealing with near-dc signals here. Resembling that in [15] and [17], \((V/I)_{\text{FD}}\) uses a pumping current twice that in \((V/I)_{\text{PD}}\) to ensure the FD loop dominates during frequency acquisition.

IV. EXPERIMENTAL RESULTS

The CDR circuit has been designed and fabricated in 90-nm CMOS technology. Fig. 16(a) reveals a photo of the die, which occupies 0.97 \(\times\) 0.88 mm\(^2\) including pads. With the help of the
frequency acquisition loop, the CDR is capable of operating over a range of 950 Mb/s without any external adjustment, across which no performance degradation is observed. Error-free operation (BER $< 10^{-12}$) for $2^{33} - 1$ PRBS input is achieved for supply voltage varying from 1.3 to 1.7 V (nominally it is 1.5 V). The circuit is carefully designed to make sure no more than 1.2 V is applied across any device. The circuit consumes a total power of 154 mW from a 1.5-V supply, of which 65 mW is dissipated in the PD, 66 mW in the VCO and clock buffers, and 23 mW in the FD. The single-ended input sensitivity is about 1 Vpp. Fig. 16(c) reveals the input waveform captured from the output of MP1803A. The jitter measures 772 fs rms and 6.67 ps pp, respectively.

Fig. 17 shows the tuning range of the VCO and the locked spectrum of the output clock. The phase noise measures $-105$ dBc/Hz at 1-MHz offset. The phase noise plots of the free-running VCO, the phase-locked VCO, and the input data are shown in Fig. 18. The loop bandwidth of the CDR can be clearly identified as 15 MHz, which corresponds to an optimal jitter performance in our design. As expected, the noise of the recovered clock follows that of the input tightly at low offset frequencies, and approaches the free-running profile after the

| TABLE I |
| CDR PERFORMANCE SUMMARY |

<table>
<thead>
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<th>[22]</th>
<th>[23]</th>
<th>[24]</th>
<th>This Work</th>
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<tbody>
<tr>
<td>Data Rate</td>
<td>12.5 Gb/s</td>
<td>25 Gb/s</td>
<td>12.5 Gb/s</td>
<td>20 Gb/s</td>
</tr>
<tr>
<td>Operation Range</td>
<td>300 Mb/s</td>
<td>6.1 Mb/s</td>
<td>2.55 Gb/s</td>
<td>950 Mb/s</td>
</tr>
<tr>
<td>PD Type</td>
<td>Linear, Half-Rate</td>
<td>Linear, Half-Rate</td>
<td>Linear, Half-Rate</td>
<td></td>
</tr>
<tr>
<td>Rec. Clock Jitter</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
<td>N/A</td>
</tr>
<tr>
<td>Rec. Data Jitter</td>
<td>N/A</td>
<td>2.11 ps, rms</td>
<td>6 ps, pp</td>
<td></td>
</tr>
<tr>
<td>BER</td>
<td>$&lt; 10^{-12}$ (with $2^{33} - 1$ PRBS)</td>
<td>$&lt; 10^{-12}$ (with $2^{33} - 1$ PRBS)</td>
<td>$&lt; 10^{-12}$ (with $2^{33} - 1$ PRBS)</td>
<td>$&lt; 10^{-13}$ (with $2^{33} - 1$ PRBS)</td>
</tr>
<tr>
<td>Jitter Tolerance</td>
<td>Exceeds OC-192 mask by 0.24 UIpp</td>
<td>Exceeds extrapolated SONET mask by 0.2 UIpp</td>
<td>Exceeds OC-192 mask by 0.2 UIpp</td>
<td>Exceeds extrapolated OC-192 mask by 0.43 UIpp</td>
</tr>
<tr>
<td>Freq. Acquisition</td>
<td>Yes (External ref. clock)</td>
<td>No</td>
<td>Yes (External ref. clock)</td>
<td>Yes (Referenceless)</td>
</tr>
<tr>
<td>Supply</td>
<td>1.2 V</td>
<td>1.1 V</td>
<td>1.5 V</td>
<td>1.5 V</td>
</tr>
<tr>
<td>Power Diss.</td>
<td>351 mW</td>
<td>172 mW</td>
<td>400 mW</td>
<td>154 mW*</td>
</tr>
<tr>
<td>Chip Area</td>
<td>N/A</td>
<td>0.32 x 0.22 mm$^2$</td>
<td>1.5 x 0.75 mm$^2$</td>
<td>0.97 x 0.88 mm$^2$</td>
</tr>
<tr>
<td>Technology</td>
<td>0.1-μm CMOS</td>
<td>90-nm CMOS</td>
<td>0.13-μm CMOS</td>
<td>90-nm CMOS</td>
</tr>
</tbody>
</table>

* Without I/O buffers.
loop bandwidth. Jitter generation is obtained as 475 fs,rms by integrating the phase noise from 100-Hz to 1-GHz offset frequencies (the maximum range for our equipments.) If we extrapolate the OC-192 specifications, the jitter generation from 100-kHz to 160-MHz offsets would be 351 fs,rms. Fig. 19(a) depicts the waveforms of the recovered data in response to a PRBS of $2^{31} - 1$, suggesting data jitter of 1.22 ps,rms and 7.56 pp, respectively. The time-domain measurement verifies the jitter generation.

To verify the signal integrity, we have also conducted jitter tolerance testing. Due to the lack of 20-Gb/s jitter tolerance tester, we measure it manually by modulating the system clock generator (MG3696B) and capture the BER accordingly. Note that an external modulation source (33250A) is required for high-frequency modulation, since MG3696B only allows internal modulation up to 1 MHz. With the error threshold set to 10$^{-12}$, we plot the jitter tolerance profile in response to an input data of $2^{7} - 1$ PRBS along with the extrapolated OC-192 specification mask. As plotted in Fig. 20, the measured jitter tolerance exceeds at least 0.43 U_{\text{IP}}$ for all jitter frequencies. Table I summarizes the performance of this work and some other similar CDR circuits recently published in the literature.

V. CONCLUSION

This work proposes a CDR with mixer-based phase detector that allows linear phase comparison up to 20 Gb/s without causing dead zone. A new frequency monitoring loop makes use of the existing data phases from the phase detector to dynamically ensure frequency locking. Peaking and mm-wave techniques are extensively utilized to extend the bandwidth and maintain the signal integrity. Providing superior performance with reasonably low power consumption, this chip demonstrates a promising future for CMOS high-speed communications.

REFERENCES


Jiří Lee (S’03–M’04) received the B.Sc. degree in electrical engineering from National Taiwan University (NTU), Taipei, Taiwan in 1995, and the M.S. and Ph.D. degrees in electrical engineering from the University of California, Los Angeles (UCLA), both in 2003. His current research interests include high-speed wireless and wireline transceivers, phase-locked loops, and data converters.

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